Synthesis and Characterization of Praseodymium Doped Nickel Zinc Ferrites using Microemulsion Method

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ABSTRACT

Spinel ferrites nanoparticles are plays important role in our daily life. Praseodymium doped Nickel Zinc Ferrite Nanoparticles having general formula Ni₀.3Zn₀.7PrₓFe₂₋ₓO₄ (x=0.00, 0.025, 0.050, 0.075 and 0.1) were synthesized by microemulsion method. X-Ray diffraction (XRD) was used to find different parameters of crystalline size. The development of the FCC spinel structure was observed by XRD data. The most intense peak of the XRD was identified at 2θ=35º. From Debye sherrer’s formula, calculated the crystalline size 15nm to 29nm ranges. The lattice constant calculations are decreased with the doping of Praseodymium (Pr³⁺) contents. The x-ray density increases as the concentration of Praseodymium (Pr³⁺) doping increases, Because Praseodymium (Pr³⁺) ion has a greater molar weight than Fe³⁺ ion. The Absorption band spectra are analyzed by using Fourier Transform Infrared spectroscopy (FTIR). The absorption bands υ₁ is known as octahedral stretching bands were found to be in the range of 414 cm⁻¹ and υ₂ is the tetrahedral stretching band were found to be in the range of 530cm⁻¹. Dielectric properties of Praseodymium doped Nickel-Zinc Ferrite were measured with impedance Analyzer in the frequency of 1 MHz to 3 GHz range. When Pr³⁺ content concentration increases, the dielectric characteristics, such as dielectric constant, dielectric loss, and tangent loss were also decreased. These measured dielectric characteristics showed that these nanomaterials may be used in higher frequencies devices.

1. Introduction

Developments in nanotechnology have revealed a successful applications for several materials that will be used in advanced technologies (Ahmed, Bishay, & Radwan, 2002). Ferrites have attracted the attention of scientists and researchers due to their numerous applications in transformer cores, magnetic memories, high-frequency circuits, and electronic circuits. Semiconductors and magnetic materials have unique features, and they are used in a variety of electrical device (Muhammad Azhar Khan, Islam, Ishaque, & Rahman, 2012). The chemical formula for spinel ferrites is AB₂O₄ (Lodhi et al., 2014). Many methods have been developed to improve the fundamental features of nano-ferrites by including other metal ions and using different production techniques. Rare earth ions are an excellent substitute for increasing spinel ferrites characteristics (M Azhar Khan, Islam, Ishaque, & Rahman, 2011). Soft Ni-Zn ferrites are inexpensive materials with intriguing electrical and magnetic properties. Microwave devices such as isolators, transformers,
circulators have all used these ferrites (Al-Hilli, Li, & Kassim, 2009). Chemical composition, annealing process, and kind of doped metal ions all influence the inherent properties of ferrites, such as permittivity, dielectric losses, and conductivity (Al-Hilli, Li, & Kassim, 2012; Jing, Liangchao, & Feng, 2007). Several synthetic processes, including as coprecipitation, sol–gel, microemulsion, ceramic, and hydrothermal methods are used to produce high-quality doped praseodymium spinel ferrites (Sun & Sun, 2007). The rare earth doped Nickel–Zinc ferrites are prominent. Due to their significance in microwave devices. The incorporation of metal ions with larger ionic radii into the spinel structure results in structural distortion as well as changes in electrical and dielectric features. In compared to other simple ferrites, the different forms of substitution in Nickel–Zinc ferrites indicate a reasonably good relaxation and conduction mechanism (Iqbal, Islam, Ali, Sadiq, & Ali, 2014). According to researches, different rare earth ions doping modifies the behaviour of spinel ferrites (Al-Hilli et al., 2012). Furthermore, doping rare earth elements in these nanomaterials can improve electrical properties and optical properties. A lot of study has gone into changing the characteristics of ferrites by doping rare earth cations in these ferrites (Sun & Sun, 2007). The influence of Pr$^{3+}$ concentration on structural, spectral, and dielectric properties has been presented in this work. Ni$_{0.3}$Zn$_{0.7}$Pr$_{x}$Fe$_{2-x}$O$_4$ (x = 0.0, 0.025, 0.05, 0.075 and 0.1) spinel ferrites was prepared via a micro-emulsion technique. The purpose of this research is to improve the structural and dielectric properties of these nanocrystalline ferrites so that they can be used in the manufacture of microwave devices (Junaid et al., 2016).

2. Experimental Procedure

Praseodymium doped Nickel–Zinc ferrites with general formula Ni$_{0.3}$Zn$_{0.7}$Pr$_{x}$Fe$_{2-x}$O$_4$ (x = 0.0, 0.025, 0.05, 0.075 and 0.1) was synthesized by using Microemulsion Method. This method was useful because it reduces cation nucleation compared to other methods such as sol-gel and co-precipitation. The chemicals were used for preparation of solution are as follows: Nickel nitrate-6 hydrate (Ni(NO$_3$)$_3$.6H$_2$O)(M.W=290.81)(99%), Zinc Nitrate Hexahydrate (ZnO6Zn.6H$_2$O)(M.W=297.46)(98%), Praseodymium Nitrate Hexahydrate (N$_3$O$_3$Pr.H$_2$O) (M.W=435.01)(99.99%), Iron(III) Nitrate9 hydrate (FeN$_3$O$_9$.9H$_2$O) (M.W=404 ) (98%), Cetyltrimethylammonium bromide (C$_{19}$H$_{37}$BrN) (M.W=346.45) (99%) were weighted using precise digital balance. The Praseodymium, Nickel, Zinc and iron sample solutions were prepared in distilled water, then combined to produce the mixed solution. The magnetic stirrer was used to stir the solution at 50°C. CTAB solution was added to the mixture of the solution. Aqueous ammonia solution was added to maintain the PH value up to 10. The mixture of all samples were stirred continuously for 5 hours. After stirring, all of the Ni$_{0.3}$Zn$_{0.7}$Pr$_{x}$Fe$_{2-x}$O$_4$ solutions were placed in the cupboards overnight. During this time, the precipitation was settled down. To reduce the value of PH, all samples were washed with deionized distilled water. The washing was carried out until the PH value reached a neutral level of 7. To remove the water, the samples of various compositions were dried in a thermostat oven at about 80 °C. Methanol was used to clean and wash the mortar and pestle before grinding. The samples were ground in a mortar and pestle after drying. After each grinding, the mortar and pestle were washed and dried to avoid contamination. All samples were placed in muffle furnace for annealing at 700°C for 3 hours. The samples was pelletized with a 4.5 ton pressure by using Hydraulic press. The prepared ferrites samples were characterized by using different characterization techniques, The XRD was done using a PANalytical Xpert Pro to examine the crystal structure and determine numerous crystalline structure parameters. The Tetrahedral and octahedral stretching bands were investigated using FTIR. The dielectric characteristics of synthesized ferrite material were investigated using an impedance analyzer. Different dielectric properties, including as the dielectric constant, dielectric loss, tangent loss, AC conductivity, real and imaginary parts of impedance, and modulus, were calculated in the frequency range of 1MHz to 3GHz, and their variations were investigated as Pr$^{3+}$ content increased.

3. Results and Discussion

3.1. XRD Analysis

Praseodymium doped Nickel Zinc Ferrite Nanoparticles having general formula Ni$_{0.3}$Zn$_{0.7}$Pr$_{x}$Fe$_{2-x}$O$_4$ (X=0.00, 0.025, 0.05, 0.075and 0.1) was effectively prepared by microemulsion technique. The samples were annealed at temperature of 700°C for 5hours.
XRD was used to analysis crystal structure and the formation of crystalline phase powder, which is a very useful technique for calculating crystalline parameters such as crystalline size, lattice constant, bulk density, x-Ray density and dislocation density etc. The XRD pattern shows very sharp peaks, indicating the formation of the crystalline phase of Nickel-Zinc ferrite. The most intense peak on the XRD was identified at 2θ=35º, which is considered to be the most intense peak for cubic spinel structure. The peaks that correspond to the XRD trend are evaluated and assigned the numbers (220), (311), (400), (422), (511), (440), and (531) correspondingly. The FCC spinel structure is defined by these peaks. JCPDS card number 22-1086 confirms these peaks. Two impurity peaks can be seen, one at 2θ =33.27º and the other at 2θ =49.54º. These impurity peaks could be caused by Pr$^{3+}$ insolubility in the octahedral site (Sheikh et al., 2019).

The crystalline size of the prepared ferrites can be determined by using the Debye sherrer's formula given as:

$$D_m = \frac{k \lambda}{\beta \cos \theta}$$  \hspace{1cm} (1)

In the above equation 'k' is equal to 0.9 (constant), \( \lambda \) is wavelength of x-ray in Å, \( \beta \) is FWHM for intense peak of XRD, \( \theta \) is the Bragg diffraction angle. The crystalline size was determined to be in the 15nm to 29nm range. With the substitution of Pr$^{3+}$, the crystalline size varied in an inhomogeneous form. This inhomogeneous behavior of crystalline size is due to the formation of a secondary phase (Warsi et al., 2017).

The Nelson Relay Function determines the lattice constant as a function of Pr$^{3+}$ concentration, which is given as:

$$a = d \left( h^2 + k^2 + l^2 \right)^{1/2}$$ \hspace{1cm} (2)

Where 'hkl' is the index of the XRD reflection peak and 'd' is the interplanar spacing. The Average lattice constant in the range of 8.360Å–8.380Å. First Lattice constant decreases with increase of Pr$^{3+}$ substitution ion contents and then increases, finally at the end Lattice constant decreases (Aslam et al., 2019). The X-ray density of the prepared nanoferrites was calculated by using the following formula as:

$$\rho_x = \frac{8M}{N_A a^3}$$ \hspace{1cm} (3)

Where 'M' denotes molecular weight, 'NA' denotes Avogadro's number, and \( a^3 \) denotes the lattice constant. The X-ray density varies from 5.39 to 5.62 g/cm$^3$ depends upon the concentration. It is also observed that X-Ray Density and concentration are approximately linear. As Pr$^{3+}$ concentration is increased, X-Ray density also increased (Gao, Wang, Pei, & Zhang, 2018). The Bulk density was calculated by using the formula give as:

$$\rho_m = \frac{m}{v}$$ \hspace{1cm} (4)

Where 'm' is mass of prepared pellets and 'v' is volume of the prepared pellets. Bulk Density varies between 3.07 to 3.58 g/cm$^3$. Bulk Density shows an in-homogeneous variance with concentration. The bulk density first increases then decreases and then again increases and the end it again decreases due to the concentration of pr$^{3+}$ doping. The Lattice strain (\( \varepsilon \)) of the ferrites was determined by formula given as:

$$\varepsilon = \frac{\beta}{4 \tan \theta} \left( 10^{-3} \right)$$ \hspace{1cm} (5)

The Lattice strain was calculated to be in the range of 3.92 \( \times 10^{-3} \) to 7.19 \( \times 10^{-3} \). The Lattice strain was found to be increases in-homogeneously with respect to concentration of Pr$^{3+}$ substituent. The value of Lattice strain is maximum at \( x = 0.075 \) and then decreases. The Micro-strain of prepared Ferrites was calculated by using the following formula:

Micro-strain = \( \beta \times \cos \theta / 4 \left( 10^{-3} \right) \) \hspace{1cm} (6)

Where \( \beta \) is FWHM of most intense peak XRD. The Micro Strain Values was calculated to be in the range of 1.16 \( \times 10^{-3} \) to 2.18 \( \times 10^{-3} \). The Micro-stain was found to be increases
with respect to concentration of $\text{Pr}^{3+}$ substituent. The Micro-Strain value is maximum at concentration of $\text{Pr}^{3+}$ substituent is at $x = 0.075$. The Dislocation density of prepared samples was determined by following formula:

$$d = \frac{1}{D^2} \times 10^{15}$$  \hfill (7)

**Figure 1:** XRD analysis of $\text{Ni}_{0.3}\text{Zn}_{0.7}\text{Pr}_x\text{Fe}_{2-x}\text{O}_4$ ($x=0.00, 0.025, 0.050, 0.075$ and $0.1$)

Where ‘D’ is the crystalline size, The Dislocation Density was measured to be in the range of $4.20 \times 10^{15}$ to $7.27 \times 10^{15}$. The Dislocation density was found to be increases with respect to concentration of $\text{Pr}^{3+}$ substituent. The Dislocation density value is maximum at concentration of $\text{Pr}^{3+}$ substituent is at $x= 0.075$. The Stacking Fault of the prepared nanoparticles is calculated by the formula:

$$\text{Stacking Fault} = \frac{2 \pi}{4 \sqrt{3} \tan(\theta)}$$

(8)

The stacking fault was observed to be decreases and then increases to a certain value, and again finally decreases. This inhomogeneous behaviour of the Stacking Fault is due to annealing temperature (Brightlin & Balamurugan, 2016).

**Figure 2:** Concentration Vs Crystalline size of $\text{Ni}_{0.3}\text{Zn}_{0.7}\text{Pr}_x\text{Fe}_{2-x}\text{O}_4$ ($x=0.00, 0.025, 0.050, 0.075$ and $0.1$)
Table 1
Different structural parameters of XRD for composition of \( \text{Ni}_{0.3}\text{Zn}_{0.7}\text{Pr}_{x}\text{Fe}_{2-x}\text{O}_4 \) 
\( (x=0.00, 0.025, 0.050, 0.075 \text{ and } 0.1) \)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>( x = 0 )</th>
<th>( x = 0.025 )</th>
<th>( x = 0.05 )</th>
<th>( x = 0.075 )</th>
<th>( x = 0.1 )</th>
</tr>
</thead>
<tbody>
<tr>
<td>Crystalline size (nm)</td>
<td>29.672</td>
<td>24.920</td>
<td>23.133</td>
<td>18.852</td>
<td>24.414</td>
</tr>
<tr>
<td>Lattice constant (Å)</td>
<td>8.379</td>
<td>8.371</td>
<td>8.367</td>
<td>8.374</td>
<td>8.360</td>
</tr>
<tr>
<td>Cell Volume (Å³)</td>
<td>588.295</td>
<td>586.507</td>
<td>585.843</td>
<td>587.306</td>
<td>584.358</td>
</tr>
<tr>
<td>X-Ray Density (g/cm³)</td>
<td>5.398</td>
<td>5.463</td>
<td>5.517</td>
<td>5.552</td>
<td>5.628</td>
</tr>
<tr>
<td>Bulk Density (g/cm³)</td>
<td>3.0738</td>
<td>3.4262</td>
<td>3.2135</td>
<td>3.5834</td>
<td>3.4429</td>
</tr>
<tr>
<td>Lattice Strain ( 10^{-3} )</td>
<td>3.92261</td>
<td>4.55211</td>
<td>4.9105</td>
<td>7.1933</td>
<td>4.6544</td>
</tr>
<tr>
<td>Micro Strain ( x 10^{-3} ) (lines/m)</td>
<td>1.1678</td>
<td>1.3904</td>
<td>1.49786</td>
<td>2.18945</td>
<td>1.4192</td>
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<td>Dislocation Density ( x 10^{15} ) (lines/m²)</td>
<td>4.2079</td>
<td>5.0194</td>
<td>4.5202</td>
<td>7.2736</td>
<td>6.0952</td>
</tr>
<tr>
<td>Stacking Fault</td>
<td>0.4473</td>
<td>0.4467</td>
<td>0.4470</td>
<td>0.4475</td>
<td>0.4471</td>
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</tbody>
</table>

3.2. FTIR Spectroscopy

Fourier Transform Infrared Spectroscopy (FTIR) is a technique used to investigate spinel crystal structure of the prepared sample of composition \( \text{Ni}_{0.3}\text{Zn}_{0.7}\text{Pr}_{x}\text{Fe}_{2-x}\text{O}_4 \) \( (x=0.00, 0.025, 0.050, 0.075 \text{ and } 0.1) \). The FTIR spectra shows two frequency bands, one of which is higher frequency band \( \nu_2 \) at around 530 cm\(^{-1}\) and the second is lower frequency band \( \nu_1 \), at around 400 cm\(^{-1}\). These samples have cubic spinel structure since the two main absorption bands \( \nu_1 \) is known as octahedral stretching bands are found to be in the range of 414 cm\(^{-1}\) and \( \nu_2 \) is the tetrahedral stretching band are found to be in the range of 530 cm\(^{-1}\). The tetrahedral and octahedral frequency bands are investigated in this analysis. Because of the tetrahedral site of intrinsic stretching vibrations, the absorption peaks are called high frequency bands \( \nu_1 \). Octahedral stretching bands are covered by low frequency band \( \nu_2 \) (Batoo et al., 2017). The characteristics feature of spinel ferrite structure are shown in these bands. It is observed that low frequency band \( \nu_1 \) value remains static. The lattice constant variations were responsible for the slight shift of high frequency band \( \nu_2 \) and low frequency band \( \nu_2 \) towards higher frequency bands with an increase in \( \text{Pr}^{3+} \) constituent. The \( \text{Fe}^{3+} \)-O\(^{2-} \) stretching vibrations were influenced by the change in lattice constant, resulting in a shift in band position (Gilani et al., 2015). The tetrahedral and octahedral sites for force constants \( K_0 \) and \( K_t \) have been calculated using the following relations:

\[
K_0 = 0.942128M (\nu_2)^2 / (M+32) \\
K_t = \sqrt{2K_0 \nu_1 / \nu_2}
\]

Where ‘\( M \)’ is molecular weight of prepared samples, \( \nu_1 \) and \( \nu_2 \) are the frequency bands. The tetrahedral and octahedral Radii was calculated by using the following formulas:

\[
R_t = a\sqrt{3} (u-0.25) - Ro \\
R_o = a (5/8-u) - Ro
\]

Where ‘\( a \)’ is lattice constant and ‘\( u \)’ is oxygen positional parameter, the value of oxygen positional parameter is 0.375.

Table 2
Different parameters in FTIR studies

<table>
<thead>
<tr>
<th>Parameters</th>
<th>( x = 0.0 )</th>
<th>( x = 0.025 )</th>
<th>( x = 0.05 )</th>
<th>( x = 0.075 )</th>
<th>( x = 0.1 )</th>
</tr>
</thead>
<tbody>
<tr>
<td>Molecular weight (gm/mol)</td>
<td>239.06402</td>
<td>241.19059</td>
<td>243.31715</td>
<td>245.44372</td>
<td>247.57029</td>
</tr>
<tr>
<td>( \nu_1 ) (cm(^{-1}))</td>
<td>540</td>
<td>537</td>
<td>540</td>
<td>537</td>
<td>540</td>
</tr>
<tr>
<td>( \nu_2 ) (cm(^{-1}))</td>
<td>414</td>
<td>414</td>
<td>414</td>
<td>414</td>
<td>414</td>
</tr>
<tr>
<td>( K_0 ) (dyne/cm(^{-1})) ( \times 10^5 )</td>
<td>1.424141</td>
<td>1.425625</td>
<td>1.427086</td>
<td>1.428524</td>
<td>1.429941</td>
</tr>
<tr>
<td>( K_t ) (dyne/cm(^{-1})) ( \times 10^5 )</td>
<td>2.627008</td>
<td>2.615135</td>
<td>2.63244</td>
<td>2.620454</td>
<td>2.637707</td>
</tr>
<tr>
<td>( R_t )</td>
<td>0.080733</td>
<td>0.079958</td>
<td>0.079649</td>
<td>0.080419</td>
<td>0.080488</td>
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<tr>
<td>( R_o )</td>
<td>0.052232</td>
<td>0.051561</td>
<td>0.051293</td>
<td>0.05196</td>
<td>0.05202</td>
</tr>
</tbody>
</table>
3.3. Dielectric Properties

The dielectric properties of synthesized Praseodymium doped Ni-Zn Ferrite Nanoparticles having general formula Ni$_{0.3}$Zn$_{0.7}$Pr$_x$Fe$_{2-x}$O$_4$ ($x=0.00, 0.025, 0.050, 0.075,$ and 0.1) were measured using an impedance analyzer. These characteristics are critical in determining the prepared ferrite is suitable for use in ultra-high-frequency devices. The synthesis technique, material composition, and cation orientation all affect these properties. The dielectric characteristics of synthesized ferrite nanoparticles were determined from 1 MHz to 3 GHz (Parveen et al., 2019).

3.3.1. Dielectric Constant and Dielectric Loss

The Figure 4(a) and Figure 4(b) shows the dielectric constant ($\varepsilon'$) and dielectric loss ($\varepsilon''$) decreases with increasing of frequency. In electron conduction, grain boundaries had a significant impact as compared to grains at low frequencies. The free and localized charge carriers were identified based on the observed dielectric constant and losses. The normal dielectric dispersion was observed that the dielectric constant dropped as frequency raised. At low frequencies, dispersion can contribute to the polarization phenomenon. The reduction in dielectric constant was attributed to both Maxwell Wagoner's model and Koop's theory. It was thought that dielectric material was made up of well-conducting regions called grains that were separated by resistive regions called grain boundaries. Since charge carriers are displaced locally, polarization occurs between Fe$^{2+}$ and Fe$^{3+}$ at grain boundaries which are in octahedral sites. The hopping mechanism causes electrons to accumulate at grain boundaries due to high resistance, resulting in space charge polarization. Dielectric dipoles that followed the variance in applied field provided a high dielectric constant at low frequencies (Junaid et al., 2016).
Table 3
Different parameters of Dielectric properties for Ni$_{0.3}$Zn$_{0.7}$Pr$_x$Fe$_{2-x}$O$_4$ ($x = 0.00$, $0.025$, $0.050$, $0.075$ and $0.1$)

<table>
<thead>
<tr>
<th>Parameters</th>
<th>Frequency</th>
<th>$x = 0.00$</th>
<th>$x = 0.025$</th>
<th>$x = 0.05$</th>
<th>$x = 0.075$</th>
<th>$x = 0.1$</th>
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<tr>
<td>Dielectric constant</td>
<td>1MHZ</td>
<td>4.027146</td>
<td>8.191817</td>
<td>8.638792</td>
<td>8.521431</td>
<td>6.476407</td>
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<tr>
<td></td>
<td>1GHZ</td>
<td>3.684943</td>
<td>2.891025</td>
<td>3.039607</td>
<td>1.732787</td>
<td>3.506363</td>
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<tr>
<td></td>
<td>3GHZ</td>
<td>3.538591</td>
<td>2.970498</td>
<td>2.993035</td>
<td>1.748285</td>
<td>3.317121</td>
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<tr>
<td>Dielectric loss</td>
<td>1MHZ</td>
<td>1.047309</td>
<td>6.292897</td>
<td>7.818412</td>
<td>9.375467</td>
<td>3.352912</td>
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<tr>
<td></td>
<td>1GHZ</td>
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<tr>
<td></td>
<td>3GHZ</td>
<td>0.1014174</td>
<td>0.1603908</td>
<td>0.05450426</td>
<td>0.0221134</td>
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</tr>
<tr>
<td>Tangent loss</td>
<td>1MHZ</td>
<td>0.2600623</td>
<td>0.768193</td>
<td>0.9050353</td>
<td>1.100222</td>
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<td></td>
<td>1GHZ</td>
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<td>0.03039364</td>
<td>0.02725891</td>
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<td></td>
<td>3GHZ</td>
<td>0.02866039</td>
<td>0.05399459</td>
<td>0.01821036</td>
<td>0.01264863</td>
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<tr>
<td>AC conductivity</td>
<td>1MHZ</td>
<td>4.37885E-05</td>
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<td>0.00049832</td>
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<td>0.03693199</td>
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</table>

3.3.2. Tan Loss and AC Conductivity

Tan loss variance is examined that Ni$_{0.3}$Zn$_{0.7}$Pr$_x$Fe$_{2-x}$O$_4$ ($x = 0.00$, $0.025$, $0.050$, $0.075$, and $0.1$) nano ferrite is inversely proportional to the applied frequency. Tangent loss reduced as frequency increased. The conduction phenomena was connected to electron hopping between Fe$^{2+}$ and Fe$^{3+}$ ions. Since the applied and hopping frequencies were matched, the maximum loss occurred at a high frequency (Junaid et al., 2016). The variance of Tangent loss with frequency shows in the below Figure 5(a). The most important properties of dielectric materials is AC conductivity. At room temperature, the AC conductivity of Ni$_{0.3}$Zn$_{0.7}$Pr$_x$Fe$_{2-x}$O$_4$($x = 0.00$, $0.025$, $0.05$, $0.075$, and $0.1$) synthesized nanoferrites was determined in frequency range is between 1 MHz and 3 GHz. The formula for calculating AC conductivity is as follows:

$$\sigma_{ac} = (t/A) z'/ (z'^2 + z''^2)$$

From the above formula ‘t’ denotes pellet thickness, ‘A’ denotes area, $z'$ denotes the real impedance part, and $z''$ denotes the imaginary impedance part. The Figure 5(b) shows that, at lower frequency the AC conductivity of most samples have a growing pattern, but in the higher frequency region dispersive behavior of samples. According to the Maxwell Wagner theory, ferrites materials are composed of conducting grains separated by a resistive layer of grain boundaries. Reduced porosity may also be causing the increase in conductivity behavior. Conductivity has a grain boundary effect at low frequencies, while conducting effects of grains have been found at high frequencies, resulting in dispersion. Because of the impacts of grains and the hopping phenomena in Fe$^{2+}$ and Fe$^{3+}$ at octahedral sites, conductivity improves at high frequencies. As the applied field increases, the charge
carrier hopping frequency increases, resulting in an increase in ac conductivity (Junaid et al., 2016; Parveen et al., 2019).

Figure 5: (a) Tangent loss Vs Frequency (b) AC Conductivity Vs Frequency

3.4.4. Real and Imaginary Impedance

Impedance analysis is a useful method for determining the relationship between dielectric properties and microstructural composition of synthesized materials. For each of the ferrite Ni$_{0.3}$Zn$_{0.7}$Pr$_x$Fe$_{2-x}$O$_4$ ($x=0.00, 0.025, 0.05, 0.075,$ and $0.1$), the real and imaginary impedance parts was calculated, the real part of impedance as a function of Log F is shown in Figure 6 (a) and the imaginary part of impedance as a function of log F is shown in Figure 6 (b).

The following formulas are used to calculate the impedance of the real and imaginary parts.

\[ Z' = R = |Z|\cos\theta \]
\[ Z' = X = |Z|\sin\theta \]  \hspace{1cm} (14)

(15)

From the figures 6. (a) And (b), as the frequency rises, the real and imaginary parts of impedance decreases according to impedance analysis. As frequency increases, the impedance curves of all samples converged, and at higher frequencies, impedance shows constant behavior, which is attributed to the discharge of space charges. The concentration differential as well as the inhomogeneity of the applied field lead these charges to collect on grain boundaries, resulting in space charges. The real and imaginary impedance parts decrease as the field frequency increases, indicating that conductivity improves.
Figure 6: (a) Real part of Impedance Vs Log F and (b) imaginary part of Impedance Vs Log F

Table 4

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<th>Parameters</th>
<th>Frequency</th>
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3.4.5 Real and Imaginary Electric Modulus

The electric modulus describes how grains and grain boundaries influence a materials dielectric properties. Within a specific frequency range, the real (M') and imaginary (M'') parts of electric modulus are calculated by the following relation:

\[ M' = \frac{\varepsilon'}{\varepsilon'^2 + \varepsilon''^2} \]

\[ M'' = \frac{\varepsilon''}{\varepsilon'^2 + \varepsilon''^2} \] (16) (17)

The M' and M'' modulus of a prepared nanoferrites with the compositional formula \( \text{Ni}_{0.3}\text{Zn}_{0.7}\text{Pr}_x\text{Fe}_{2-x}\text{O}_4 \) \((x=0.00, 0.025, 0.05, 0.075, \text{and} 0.1) \) was measured of the applied frequency 1MHz to 3GHz ranges. Electric modulus can be used to study the electrical reaction of ferroelectric materials, which is based on the phenomenon of differential complex modulus formalism can be used to describe grain and grain boundary effects in some homogeneous materials. The electric modulus of \( \text{Ni}_{0.3}\text{Zn}_{0.7}\text{Pr}_x\text{Fe}_{2-x}\text{O}_4 \) is utilized to analyze the effects of interfacial polarization as a function of applied field frequency. The real part of electric modulus (M') is shown in the figure 7(a), and the imaginary part of electric modulus (M'') is shown in figure 7(b).

Figure 7(a) depicts the variance of the real part of modulus (M') with frequency. The value of M' increases with the increase in frequency, as seen in the graph. This is because the materials have a space charge polarization effect. The value of M' is increased then decreased at a certain frequency range of 1 MHz–3 GHz. Now from the figure 7(b) show that the Imaginary electric Modulus (M'') decreased with frequency increased. The
relationship between grain boundaries and peak formation confirms this perspective (Ditta, Khan, Junaid, Khalil, & Warsi, 2017).

4. Conclusions

Praseodymium (Pr$^{3+}$) doped Nickel–Zinc Ferrite having general formula $\text{Ni}_0.3\text{Zn}_{0.7}\text{Pr}_x\text{Fe}_{2-x}\text{O}_4$ ($x=0.00, 0.025, 0.050, 0.075$ and $0.1$) was synthesized via microemulsion technique, that is the easiest method to synthesize of such type of ferrites. The FCC spinel structure is confirmed by XRD measurements. The XRD method was used to analyze crystal structure and crystalline phase formation, and it’s a great way to find out crystalline parameters including crystalline size, lattice parameters, x-ray density, and bulk density etc. The most intense peak of the XRD was identified at $2\theta=35^\circ$. From Debye sherrer’s formula, calculated the crystalline size $15\text{nm}$ to $29\text{nm}$ ranges. Lattice constant in the range of $8.360\text{Å}−8.380\text{Å}$. The lattice parameter calculations are decreased with the doping of Praseodymium (Pr$^{3+}$) contents. Fourier Transform Infrared Spectroscopy (FTIR) technique was used to investigate spinel crystal structure of the prepared sample of composition $\text{Ni}_0.3\text{Zn}_{0.7}\text{Pr}_x\text{Fe}_{2-x}\text{O}_4$ ($x=0.00, 0.025, 0.050, 0.075$ and $0.1$). FTIR analyses reveal two frequency stretching bands $\nu_1$ and $\nu_2$ that correspond to the tetrahedral and octahedral sites respectively. The absorption bands $\nu_1$ is known as octahedral stretching bands are found to be in the range of $414\text{cm}^{-1}$ and $\nu_2$ is the tetrahedral stretching band are found to be in the range of $530\text{cm}^{-1}$. Dielectric properties of Praseodymium doped Nickel - Zinc Ferrite were measured with impedance analyzer from 1 MHz to 3 GHz frequency range. When Pr$^{3+}$ concentration increases, the dielectric characteristics, such as dielectric constant ($\epsilon'$) and dielectric loss ($\epsilon''$) and tangent loss was found to be decreases. The electric modulus describes how grains and grain boundaries influence a material’s dielectric properties. Electric modulus can be used to study the electrical reaction of ferroelectric materials, which is based on the phenomenon of electric complex modulus formalism can be used to describe grain and grain boundary effects in some homogeneous materials. These measured dielectric characteristics showed that these nanomaterials may be used in higher frequencies devices.

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